## NSN 5961-00-583-1975

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-583-1975 **Inclosure Material:** Glass and metal **Overall Length:** 0.435 inches **Overall Height:** 0.315 inches **Overall Width:** 0.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Clip and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 60.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No